



深圳市诚芯微科技股份有限公司

SHENZHEN CHENGXINWEI TECHNOLOGY CO., LTD.

N-channel Enhancement Mode Mosfet

CX4520

DESCRIPTION

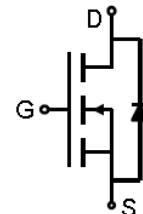
The CX4520 uses advanced trench technology to provide excellent RDS(ON) and low gate charge. This device is suitable for use as a load switch or in PWM applications.

GENERAL FEATURES

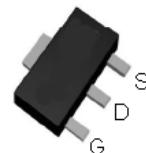
- RDS(ON) <22mΩ @ VGS=4.5V
RDS(ON) <15mΩ @ VGS=10V
- High Power and current handing capability
- Lead free product is acquired
- Surface Mount Package

Application

- PWM applications
- Load switch
- Power management



Schematic diagram



Top View SOT-89

ABSOLUTE MAXIMUM RATINGS($T_A=25^\circ\text{C}$ unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	V _{DS}	45	V
Gate-Source Voltage	V _{GS}	± 20	V
Drain Current @ Continuous (Note 2)	I _D (25°C)	30	A
	I _D (100°C)	20	A
Drain Current @ Current-Pulsed (Note 1)	I _{DM}	112	A
Maximum Power Dissipation ($T_A=25^\circ\text{C}$)	P _D	35	W
Operating Junction and Storage Temperature Range	T _J , T _{STG}	-55 To 150	°C

THERMAL CHARACTERISTICS

Thermal Resistance, Junction-to-Ambient (Note 2)	R _{θJA}	35	°C/W
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